TOSHIBA 2SC2782

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

2 S C 2 7 8 2

VHF BAND POWER AMPLIFIER APPLICATIONS

• Output Power: Po=80W (Min.) (f=175MHz, V_{CC}=12.5V, Pi=18W)

MAXIMUM RATINGS (Tc = 25°C)

| CHARACTERISTIC | SYMBOL | RATING | UNIT |
|-----------------------------|------------------|---------|------|
| Collector-Base Voltage | v_{CBO} | 36 | V |
| Collector-Emitter Voltage | v_{CEO} | 16 | V |
| Emitter-Base Voltage | $V_{ m EBO}$ | 4 | V |
| Collector Current | $I_{\mathbf{C}}$ | 20 | A |
| Collector Power Dissipation | PC | 220 | W |
| Junction Temperature | Tj | 175 | °C |
| Storage Temperature Range | $T_{ m stg}$ | -65~175 | °C |

2-13C1A

TOSHIBA Weight: 5.5g

EIAJ

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

| CHARACTERISTIC | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-------------------------------------|-----------------------|--|------|--------------|------|------|
| Collector-Base Breakdown Voltage | V _(BR) CBO | $I_{C} = 20 \text{mA}, I_{E} = 0$ | 36 | _ | _ | V |
| Collector-Emitter Breakdown Voltage | | $I_{C} = 50 \text{mA}, I_{B} = 0$ | 16 | _ | _ | V |
| Emitter-Base Breakdown Voltage | V _{(BR)EBO} | $I_E=1mA, I_C=0$ | 4 | _ | _ | V |
| DC Current Gain | $h_{	extbf{FE}}$ | $V_{CE}=5V, I_{C}=10A$ * | 10 | _ | _ | |
| Collector Output Capacitance | Cob | $V_{CB} = 12.5V, I_{E} = 0$ f = 1MHz | _ | _ | 320 | pF |
| Output Power | Po | (Fig.) | 80 | 90 | _ | W |
| Power Gain | Gp | V _{CC} =12.5V, f=175MHz Pi=18W | 6.4 | 6.8 | _ | dB |
| Collector Efficiency | $\eta_{\mathbf{C}}$ | | 60 | 70 | _ | % |
| Series Equivalent Input Impedance | Zin | V _{CC} =12.5V f=175MHz, Po=80W | _ | 1.0 +j1.5 | _ | Ω |
| Series Equivalent Output Impedance | Z _{out} | | | 1.2 +j1.8 | _ | Ω |

^{*} Pulse Test: Pulse Width $\leq 100 \mu$ s, Duty Cycle $\leq 3\%$

CAUTION

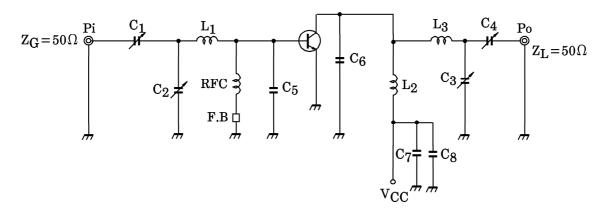
Beryllia Ceramics is used in this product. The dust or vapor can be dangerous to humans. Do not break, cut, crush or dissolve chemically. Dispose of this properly according to law. Do not intermingle with normal industrial or domestic waste.

961001EAA2

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

TOSHIBA 2SC2782

Fig. Po TEST CIRCUIT

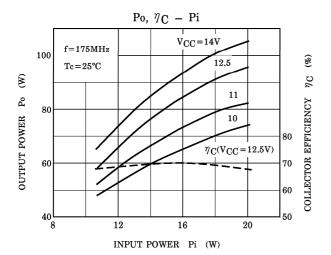


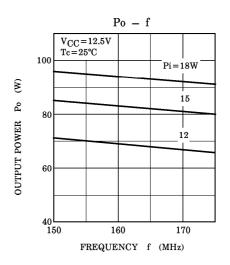
 $\begin{array}{cccc} {\rm C_{1}}{\sim}{\rm C_{4}} & : & \sim 20 {\rm pF} \\ {\rm C_{5}} & : & 156 {\rm pF} \, (\\ {\rm C_{6}} & : & 132 {\rm pF} \, (\\ {\rm C_{7}} & : & 0.01 {\rm \mu F} \\ {\rm C_{8}} & : & 10 {\rm \mu F} \\ {\rm L_{1}}, \, {\rm L_{3}} & : & \phi \, 1.5 {\rm mr} \end{array}$: 156pF (39pF×4) CERAMIC CONDENSER
 : 132pF (33pF×4) CERAMIC CONDENSER

: 0.01μ F CERAMIC CONDENSER

: ϕ 1.5mm SILVER PLATED COPPER WIRE, 10ID, 1T : ϕ 1.5mm SILVER PLATED COPPER WIRE, 10ID, 2T RFC : ϕ 1mm ENAMEL COATED COPPER WIRE, 6ID, 10T

FB: FERRITE BEAD





CAUTION

These are only typical curves and devices are not necessarily guaranteed at these curves.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.